PUMD15/ZLX Datasheet

DiGi Electronics Part Number	PUMD15/ZLX-DG
Manufacturer	Nexperia USA Inc.
Manufacturer Product Number	PUMD15/ZLX
Description	TRANS PREBIAS
Detailed Description	Pre-Biased Bipolar Transistor (BJT) 1 NPN, 1 PNP - Pre-Biased (Dual) 50V 100mA 230MHz, 180MHz 300mW Surface Mount 6-TSSOP

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
PUMD15/ZLX	Nexperia USA Inc.
Series:	Product Status:
-	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
1 NPN, 1 PNP - Pre-Biased (Dual)	100mA
Voltage - Collector Emitter Breakdown (Max):	Resistor - Base (R1):
50V	4.7kOhms
Resistor - Emitter Base (R2):	DC Current Gain (hFE) (Min) @ Ic, Vce:
4.7kOhms	30 @ 10mA, 5V
Vce Saturation (Max) @ Ib, Ic:	Current - Collector Cutoff (Max):
150mV @ 500µA, 10mA	1µA
Frequency - Transition:	Power - Max:
230MHz, 180MHz	300mW
Grade:	Qualification:
Automotive	AEC-Q101
Mounting Type:	Package / Case:
Surface Mount	6-TSSOP, SC-88, SOT-363
Supplier Device Package:	Base Product Number:
6-TSSOP	PUMD15

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	OBSOLETE
HTSUS:	
0000.00.0000	

PUMD15

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 4.7 kΩ, R2 = 4.7 kΩ

31 March 2023 **Product data sheet**

1. General description

NPN/PNP double Resistor-Equipped Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: PUMH15

PNP/PNP complement: PUMB15

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplified circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- Low current peripheral driver
- Controlling IC inputs
- Replacement of general purpose transistors in digital applications

4. Quick reference data

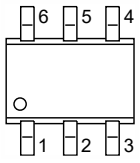
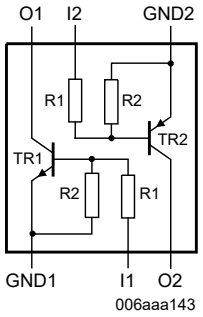
Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per transistor							
V_{CEO}	collector-emitter voltage	open base	[1]	-	-	50	V
I_O	output current		[1]	-	-	100	mA
R1	bias resistor 1 (input)		[2]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[2]	0.8	1	1.2	

[1] For the PNP transistor (TR2) with negative polarity.
[2] See section "Test information" for resistor calculation and test conditions.

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1	 TSSOP6 (SOT363)	
2	I1	input (base) TR1		
3	O2	output (collector) TR2		
4	GND2	GND (emitter) TR2		
5	I2	input (base) TR2		
6	O1	output (collector) TR1		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PUMD15	TSSOP6	plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	SOT363

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PUMD15	D0%

[1] % = placeholder for manufacturing site code

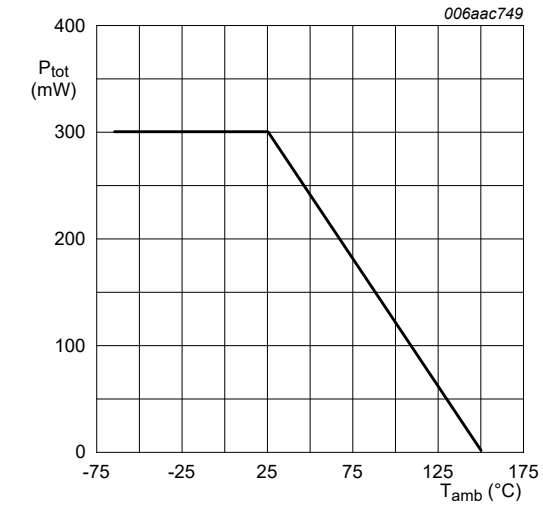
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transistor						
V_{CBO}	collector-base voltage	open emitter	[1]	-	50	V
V_{CEO}	collector-emitter voltage	open base	[1]	-	50	V
V_{EBO}	emitter-base voltage	open collector	[1]	-	10	V
V_I	input voltage	TR1 (NPN)		-10	30	V
		TR2 (PNP)		-30	10	V
I_O	output current		[1]	-	100	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C	[2]	-	200	mW
Per device						
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C	[2]	-	300	mW
T_j	junction temperature			-	150	°C
T_{amb}	ambient temperature			-65	150	°C
T_{stg}	storage temperature			-65	150	°C

[1] For the PNP transistor (TR2) with negative polarity.
[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint

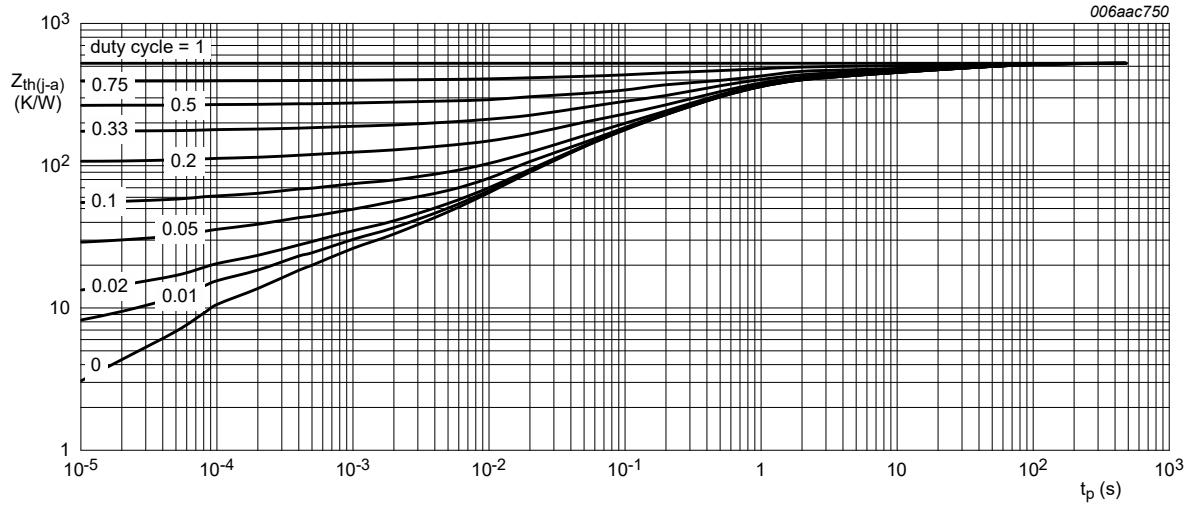
Fig. 1. Per device: Power derating curve

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint

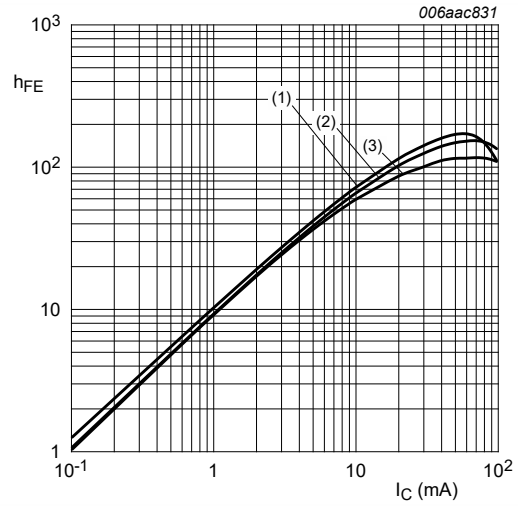
Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

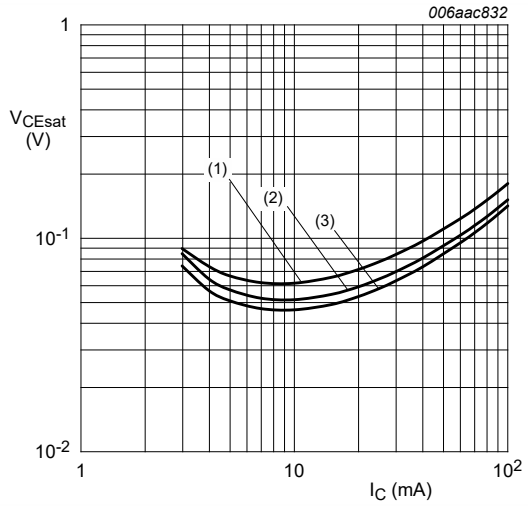
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per transistor							
$V_{(BR)CBO}$	collector-base breakdown voltage	I_C = 100 µA; I_E = 0 A; T_{amb} = 25 °C	[1]	50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	I_C = 2 mA; I_B = 0 A; T_{amb} = 25 °C	[1]	50	-	-	V
I_{CBO}	collector-base cut-off current	V_{CB} = 50 V; I_E = 0 A; T_{amb} = 25 °C	[1]	-	-	100	nA
I_{CEO}	collector-emitter cut-off current	V_{CE} = 30 V; I_B = 0 A; T_{amb} = 25 °C	[1]	-	-	100	nA
		V_{CE} = 30 V; I_B = 0 A; T_j = 150 °C	[1]	-	-	5	µA
I_{EBO}	emitter-base cut-off current	V_{EB} = 5 V; I_C = 0 A; T_{amb} = 25 °C	[1]	-	-	900	µA
h_{FE}	DC current gain	V_{CE} = 5 V; I_C = 10 mA; T_{amb} = 25 °C	[1]	30	-	-	
V_{CEsat}	collector-emitter saturation voltage	I_C = 10 mA; I_B = 0.5 mA; T_{amb} = 25 °C	[1]	-	-	150	mV
$V_{I(off)}$	off-state input voltage	V_{CE} = 5 V; I_C = 100 µA; T_{amb} = 25 °C	[1]	-	1.1	0.5	V
$V_{I(on)}$	on-state input voltage	V_{CE} = 0.3 V; I_C = 20 mA; T_{amb} = 25 °C	[1]	2.5	1.9	-	V
R1	bias resistor 1 (input)		[2]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[2]	0.8	1	1.2	
TR1 (NPN)							
C_c	collector capacitance	V_{CB} = 10 V; I_E = 0 A; i_e = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	2.5	pF
f_T	transition frequency	V_{CE} = 5 V; I_C = 10 mA; f = 100 MHz; T_{amb} = 25 °C	[3]	-	230	-	MHz
TR2 (PNP)							
C_c	collector capacitance	V_{CB} = -10 V; I_E = 0 A; i_e = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	3	pF
f_T	transition frequency	V_{CE} = -5 V; I_C = -10 mA; f = 100 MHz; T_{amb} = 25 °C	[3]	-	180	-	MHz

[1] For the PNP transistor (TR2) with negative polarity.
[2] See section "Test information" for resistor calculation and test conditions.
[3] Characteristics of built-in transistor



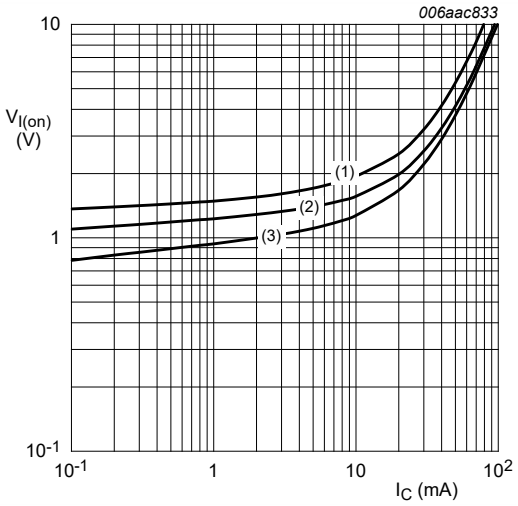
V_{CE} = 5 V
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 3. TR1 (NPN): DC current gain as a function of collector current; typical values



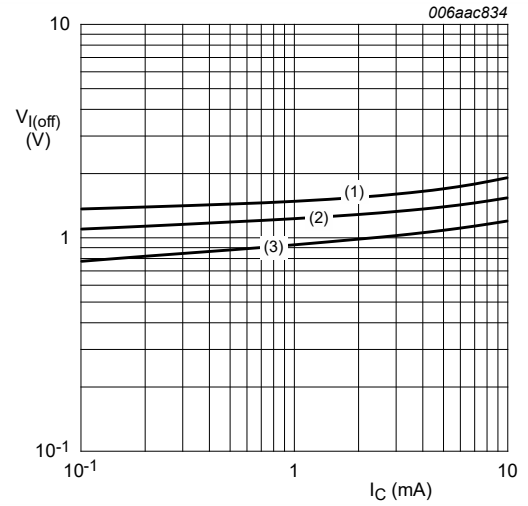
I_C/I_B = 20
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 4. TR1 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values



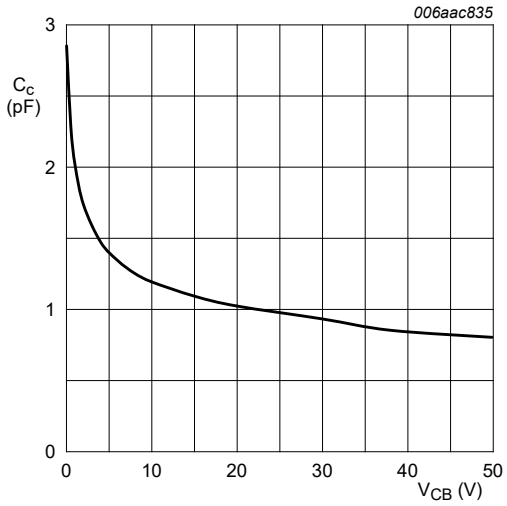
V_{CE} = 0.3 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 5. TR1 (NPN): On-state input voltage as a function of collector current; typical values



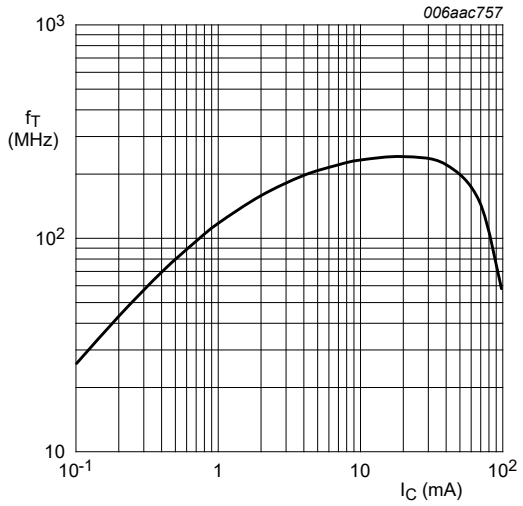
V_{CE} = 5 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 6. TR1 (NPN): Off-state input voltage as a function of collector current; typical values



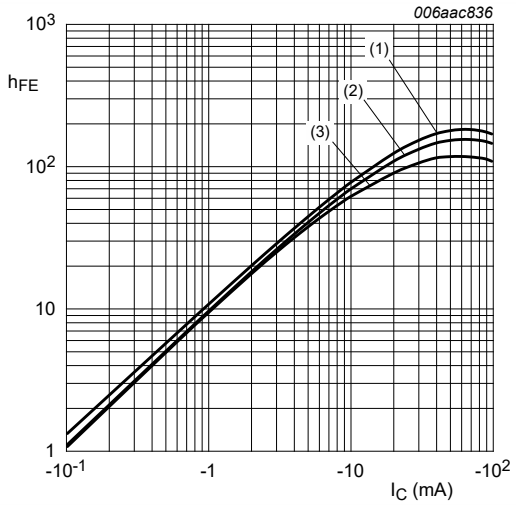
f = 1 MHz
T_{amb} = 25 °C

Fig. 7. TR1 (NPN): Collector capacitance as a function of collector-base voltage; typical values



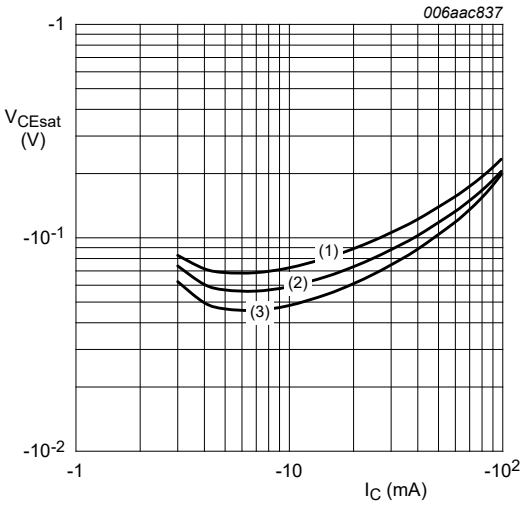
f = 100 MHz
T_{amb} = 25 °C
V_{CE} = 5 V

Fig. 8. TR1 (NPN): Transition frequency as a function of collector current; typical values of built-in transistor



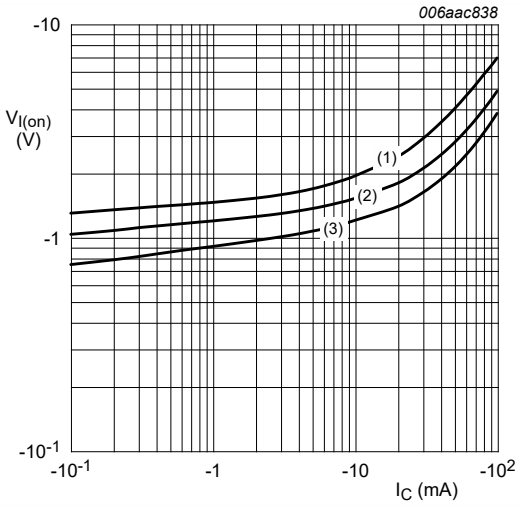
V_{CE} = -5 V
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 9. TR2 (PNP): DC current gain as a function of collector current; typical values



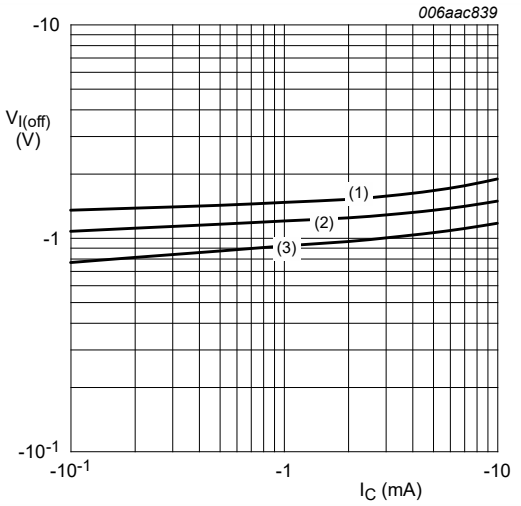
I_C/I_B = 20
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 10. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values



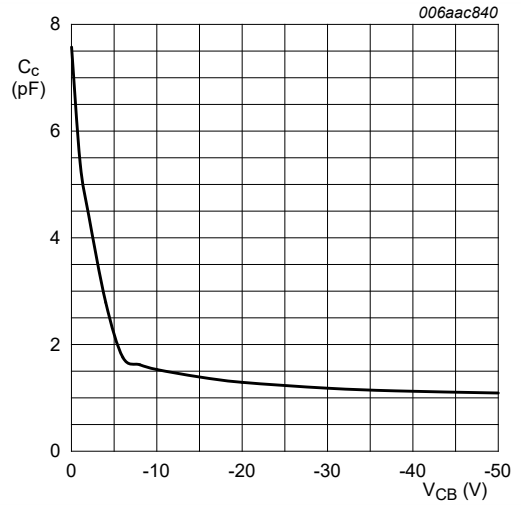
V_{CE} = -0.3 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 11. TR2 (PNP): On-state input voltage as a function of collector current; typical values



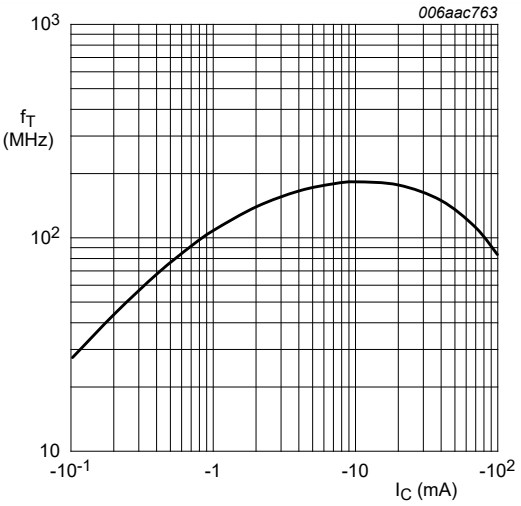
V_{CE} = -5 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 12. TR2 (PNP): Off-state input voltage as a function of collector current; typical values



f = 1 MHz
T_{amb} = 25 °C

Fig. 13. TR2 (PNP): Collector capacitance as a function of collector-base voltage; typical values



f = 100 MHz
T_{amb} = 25 °C
V_{CE} = -5 V

Fig. 14. TR2 (PNP): Transition frequency as a function of collector current; typical values of built-in transistor

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R_1 = \frac{V(I_2) - V(I_1)}{I_2 - I_1}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I_4) - V(I_3)}{R1 \cdot (I_4 - I_3)} - 1$$

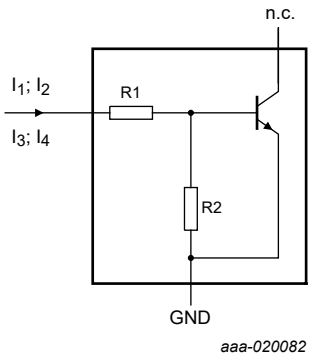


Fig. 15. NPN transistor: Resistor test circuit

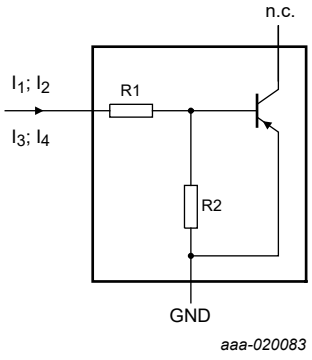


Fig. 16. PNP transistor: Resistor test circuit

Resistor test conditions

Table 8. Resistor test conditions

PUMD15	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I_1	I_2	I_3	I_4
TR1 (NPN)	4.7	4.7	600 µA	700 µA	-600 µA	-700 µA
TR2 (PNP)	4.7	4.7	-600 µA	-700 µA	600 µA	700 µA

12. Package outline

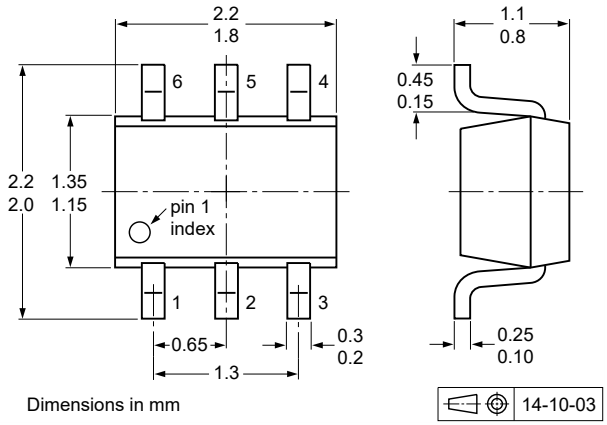


Fig. 17. Package outline TSSOP6 (SOT363)

13. Soldering

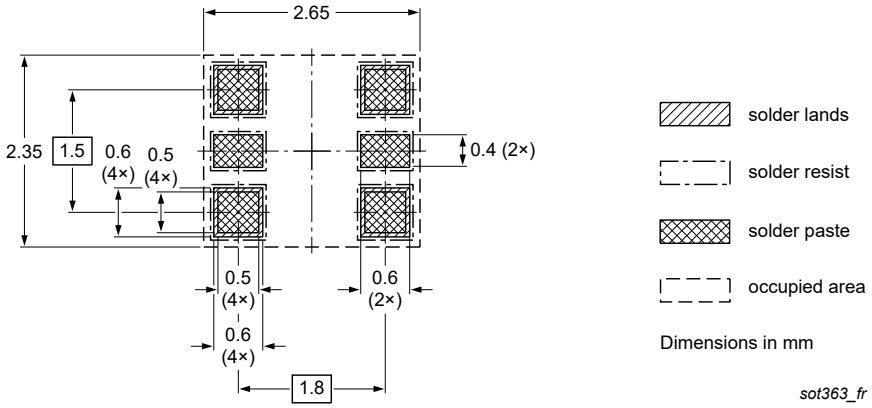


Fig. 18. Reflow soldering footprint for TSSOP6 (SOT363)

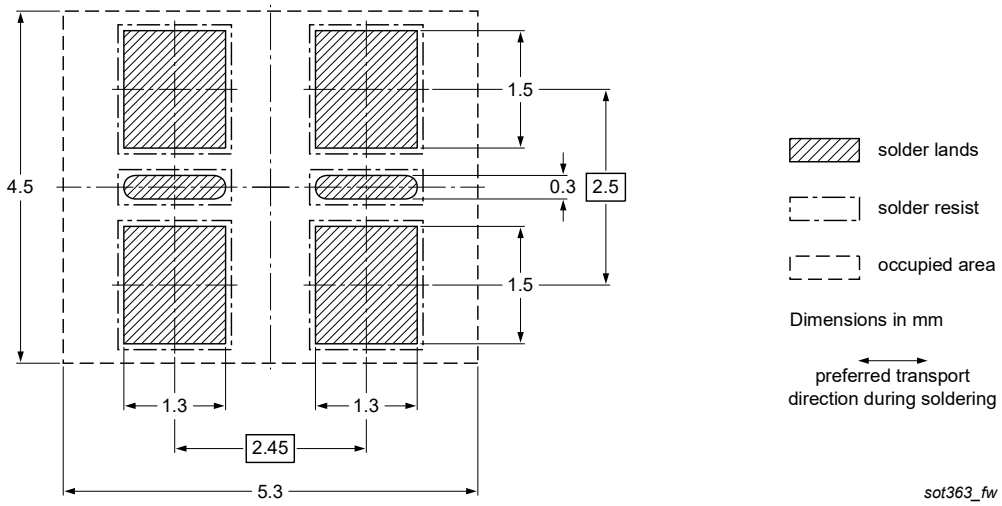


Fig. 19. Wave soldering footprint for TSSOP6 (SOT363)

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PUMD15 v.5	20230331	Product data sheet	-	PEMD15_PUMD15 v.4
Modifications:	• The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. • Legal texts have been adapted to the new company name where appropriate. • Family data sheet reduced to single type data sheet. • Packing information removed.			
PEMD15_PUMD15 v.4	20111219	Product data sheet	-	PEMD15_PUMD15 v.3
PEMD15_PUMD15 v.3	20090902	Product data sheet	-	PEMD15_PUMD15 v.2
PEMD15_PUMD15 v.2	20050425	Product data sheet	-	PUMD15 v.1
PUMD15 v.1	20040204	Product specification	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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Contents

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